Low-power D-type transparent latch; 3-state

Rev. 6 — 4 July 2012

Product data sheet

1. General description

The 74AUP1G373 provides the single D-type transparent latch with 3-state output. While the latch-enable (LE) input is high, the Q output follows the data (D) input. When pin LE is LOW, the latch stores the information that was present at the D-input one set-up time preceding the HIGH-to-LOW transition of pin LE. When pin \overline{OE} is LOW, the contents of the latch is available at the (Q) output. When pin \overline{OE} is HIGH, the output goes to the high-impedance OFF-state. Operation of input pin \overline{OE} does not affect the state of the latch.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G373GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1G373GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886
74AUP1G373GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891
74AUP1G373GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115
74AUP1G373GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 \times 1.0 \times 0.35 mm	SOT1202

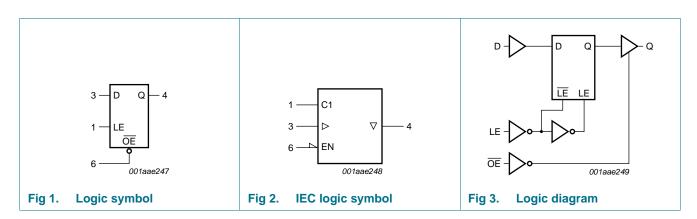
4. Marking

Table 2. Marking

Type number	Marking code ^[1]
74AUP1G373GW	aW
74AUP1G373GM	aW
74AUP1G373GF	aW
74AUP1G373GN	aW
74AUP1G373GS	aW

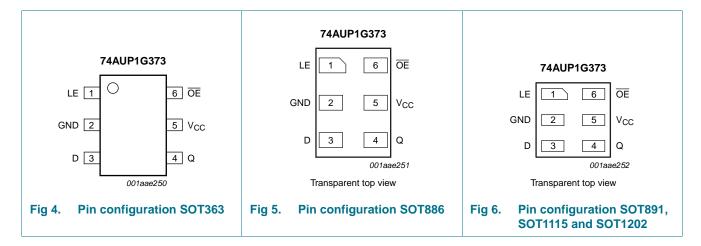
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
LE	1	latch enable input (active HIGH)
GND	2	ground (0 V)
D	3	data input
Q	4	latch output
V _{CC}	5	supply voltage
ŌE	6	output enable input (active LOW)

7. Functional description

Table 4. Function table[1]

Operating modes	Input		Internal latch	Output	
	OE	LE	D		Q
Enable and read register (transparent	L	Н	L	L	L
mode)	L	Н	Н	Н	Н
Latch and read register	L	L	I	L	L
	L	L	h	Н	Н
Latch register and disable outputs	Н	X	X	Χ	Z

^[1] H = HIGH voltage level;

h = HIGH voltage level one setup time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level;

I = LOW voltage level one setup time prior to the HIGH-to-LOW LE transition;

X = Don't care;

Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	$V_I < 0 V$	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2] -	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		8.0	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V_{CC}	V
		Power-down mode; $V_{CC} = 0 \text{ V}$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = 2$	5 °C					
V_{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	$0.70 \times V_{CC}$	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	$0.30 \times V_{CC}$	V
		V _{CC} = 0.9 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
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^[2] For SC-88 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_{O} = -20 \mu A$; $V_{CC} = 0.8 \text{ V}$ to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	٧
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	٧
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	٧
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	٧
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	٧
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	٧
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	٧
		$I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	٧
		$I_O = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.31	٧
		$I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	٧
		$I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	V
		$I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
l _l	input leakage current	$V_{I} = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μΑ
Δl _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	40	μΑ
Cı	input capacitance	$V_{CC} = 0 \text{ V to } 3.6 \text{ V; } V_{I} = \text{GND or } V_{CC}$	-	0.8	-	рF
Co	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
		output disabled; $V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_O = \text{GND or } V_{CC}$	-	1.5	-	pF
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	$0.70 \times V_{CC}$	-	-	٧
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	٧
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	٧
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V			0.9	V

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V}$ to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_O = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		$I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	$0.3 \times V_{CC}$	V
		$I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.37	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.35	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.33	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.33	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
l _{oz}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μΑ
Δl _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	50	μΑ
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	٧
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}		-	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
-		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	_	_	0.9	V

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = -20 \ \mu A; \ V_{CC} = 0.8 \ V \ to \ 3.6 \ V$	V _{CC} - 0.11	-	-	V
V _{OH} H V _{OL} L I _I in I _{OZ} C I _{OFF} p ΔI _{OFF} a I _E		$I_O = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6 \times V_{CC}$	-	-	V
		$I_O = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_O = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_O = -2.3$ mA; $V_{CC} = 2.3$ V	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_O = -4.0$ mA; $V_{CC} = 3.0$ V	2.30	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		$I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	$0.33 \times V_{CC}$	V
		$I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.41	V
		$I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.39	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μΑ
lcc	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
Δl _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	75	μΑ

^[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Symbol	Parameter	Conditions		25 °C			-40 °C 1	to +125 °C	;	Unit
			Min	Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
$C_L = 5 pl$	F			'	'	'			•	•
t _{pd}	propagation	D to Q; see Figure 7	•							
	delay	V _{CC} = 0.8 V	-	21.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.6	13.5	2.6	13.8	2.6	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.6	7.8	2.1	8.3	2.1	9.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.7	6.2	1.6	6.7	1.6	7.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.8	2.9	4.1	1.5	4.5	1.5	4.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.5	2.5	3.5	1.2	4.0	1.2	4.5	ns
		LE to Q; see Figure 8								
		V _{CC} = 0.8 V	-	20.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	6.2	13.6	2.5	14.0	2.5	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.4	7.6	2.0	8.5	2.0	9.3	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.5	5.8	1.5	6.7	1.5	7.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.6	4.0	1.3	4.4	1.3	4.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.3	2.2	3.3	1.1	3.8	1.1	4.2	ns
t _{en}	enable time	OE to Q; see Figure 10	•							
		V _{CC} = 0.8 V	-	17.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	5.1	9.2	3.0	9.2	3.0	10.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	3.8	5.8	2.4	6.1	2.4	6.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	3.3	4.8	2.0	5.0	2.0	5.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	2.7	3.8	1.8	4.0	1.8	4.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.5	3.4	1.8	3.6	1.8	4.0	ns
t _{dis}	disable time	OE to Q; see Figure 10								
		V _{CC} = 0.8 V	-	9.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	4.2	7.5	2.8	7.9	2.8	8.7	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.2	4.9	2.1	5.3	2.1	5.8	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.2	3.0	4.4	2.1	4.9	2.1	5.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.2	3.1	1.5	3.4	1.5	3.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.6	3.3	1.8	3.6	1.8	4.0	ns

Low-power D-type transparent latch; 3-state

 Table 8.
 Dynamic characteristics ...continued

Symbol	Parameter	Conditions		25 °C			-40 °C 1	to +125 °C	;	Unit
			Min	Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C _L = 10 p	οF									
t _{pd}	propagation	D to Q; see Figure 7								
	delay	$V_{CC} = 0.8 V$	-	24.4	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.0	7.5	15.3	2.7	15.9	2.7	17.4	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	2.6	5.3	9.0	2.2	9.4	2.2	10.3	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.5	4.3	6.9	2.1	7.3	2.1	8.0	ns
		V_{CC} = 2.3 V to 2.7 V	2.0	3.5	4.8	1.8	5.3	1.8	5.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.8	3.1	4.2	1.7	4.6	1.7	5.1	ns
		LE to Q; see Figure 8								
		$V_{CC} = 0.8 V$	-	23.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	2.9	7.1	15.4	2.7	16.1	2.7	17.7	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	2.5	5.0	8.8	2.1	9.5	2.1	10.4	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.3	4.1	6.6	2.0	7.3	2.0	8.1	ns
		V_{CC} = 2.3 V to 2.7 V	1.9	3.1	4.7	1.6	5.2	1.6	5.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.7	2.8	4.0	1.4	4.4	1.4	4.9	ns
t _{en}	enable time	OE to Q; see Figure 10								
		$V_{CC} = 0.8 V$	-	21.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.7	6.0	10.6	3.4	10.6	3.4	11.7	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	4.5	6.7	2.8	7.0	2.8	7.7	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.7	3.9	5.5	2.5	5.8	2.5	6.4	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.4	3.3	4.5	2.2	4.7	2.2	5.2	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.3	3.1	4.1	2.2	4.3	2.2	4.7	ns
t_{dis}	disable time	OE to Q; see Figure 10								
		V _{CC} = 0.8 V	-	11.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.9	5.3	8.7	3.8	9.2	3.8	10.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	4.1	5.8	2.9	6.2	2.9	6.8	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	4.2	5.7	3.1	6.0	3.1	6.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.0	4.0	2.2	4.3	2.2	4.7	ns
		V _{CC} = 3.0 V to 3.6 V	3.0	3.8	4.7	2.9	5.0	2.9	5.5	ns

Low-power D-type transparent latch; 3-state

 Table 8.
 Dynamic characteristics ...continued

Symbol	Parameter	Conditions		25 °C			-40 °C 1	to +125 °C	;	Unit
				Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C _L = 15 p	οF									
t _{pd}	propagation	D to Q; see Figure 7	•							
	delay	$V_{CC} = 0.8 V$	-	27.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.5	8.3	16.9	3.2	17.5	3.2	19.2	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.1	5.9	9.6	2.7	10.5	2.7	11.6	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.6	4.8	7.6	2.2	8.5	2.2	9.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.5	3.9	5.5	2.2	5.9	2.2	6.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.2	3.6	4.9	1.8	5.5	1.8	6.0	ns
		LE to Q; see Figure 8	•							
		$V_{CC} = 0.8 V$	-	26.1	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.3	7.9	17.3	3.0	18.0	3.0	19.8	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.0	5.6	9.7	2.5	10.7	2.5	11.8	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.5	4.6	7.4	2.2	8.3	2.2	9.1	ns
		V_{CC} = 2.3 V to 2.7 V	2.3	3.6	5.3	2.0	5.9	2.0	6.4	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.1	3.2	4.6	1.8	5.1	1.8	5.6	ns
t _{en}	enable time	OE to Q; see Figure 10	•							
		$V_{CC} = 0.8 V$	-	24.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.1	6.8	12.1	3.8	12.1	3.8	13.3	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	5.1	7.5	3.2	7.9	3.2	8.7	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.1	4.4	6.1	2.8	6.5	2.8	7.2	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.8	3.7	5.0	2.5	5.3	2.5	5.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.6	3.5	4.7	2.5	4.9	2.5	5.4	ns
t _{dis}	disable time	OE to Q; see Figure 10	•							
		$V_{CC} = 0.8 V$	-	13.1	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	4.9	6.5	9.8	4.8	10.4	4.8	11.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.9	5.0	6.8	3.8	7.3	3.8	8.0	ns
		V _{CC} = 1.65 V to 1.95 V	4.2	5.3	6.9	4.1	7.3	4.1	8.0	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	3.8	4.8	2.9	5.1	2.9	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	4.1	5.0	6.1	4.0	6.4	4.0	7.0	ns

 Table 8.
 Dynamic characteristics ...continued

Symbol	Parameter	Conditions		25 °C			–40 °C 1	to +125 °C	;	Unit
				Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C _L = 30 p	ρF					1			1	
t _{pd}	propagation	D to Q; see Figure 7								
	delay	V _{CC} = 0.8 V	-	35.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	10.6	22.1	3.7	23.3	3.7	25.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.5	12.3	3.5	13.6	3.5	15.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	6.2	9.5	3.2	10.5	3.2	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	3.3	5.1	6.9	2.9	7.6	2.9	8.3	ns
		V _{CC} = 3.0 V to 3.6 V	3.0	4.7	6.4	2.9	7.2	2.9	7.9	ns
		LE to Q; see Figure 8								
		V _{CC} = 0.8 V	-	34.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	10.2	22.2	3.7	23.5	3.7	25.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	7.2	12.4	3.4	13.7	3.4	15.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.3	5.9	9.5	3.0	10.5	3.0	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	3.1	4.8	6.8	2.7	7.5	2.7	8.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	4.4	6.1	2.6	7.0	2.6	7.7	ns
t _{en}	enable time	OE to Q; see Figure 10								
		V _{CC} = 0.8 V	-	34.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.5	9.1	16.2	4.9	16.2	4.9	17.8	ns
		V _{CC} = 1.4 V to 1.6 V	4.6	6.7	9.9	4.2	10.5	4.2	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	4.2	5.7	7.9	3.7	8.6	3.7	9.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	3.6	4.9	6.4	3.4	6.9	3.4	7.6	ns
		V _{CC} = 3.0 V to 3.6 V	3.4	4.7	6.1	3.3	6.5	3.3	7.2	ns
t _{dis}	disable time	OE to Q; see Figure 10								
		V _{CC} = 0.8 V	-	19.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	8.0	9.9	13.7	7.9	14.5	7.9	16.0	ns
		V _{CC} = 1.4 V to 1.6 V	6.3	7.7	9.7	6.2	10.5	6.2	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	7.3	8.7	10.6	7.2	11.3	7.2	12.4	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	5.2	6.2	7.5	5.1	7.8	5.1	8.6	ns
		V _{CC} = 3.0 V to 3.6 V	7.5	8.8	10.2	7.4	10.5	7.4	11.6	ns
C _L = 5 pl	F, 10 pF, 15 pl	F and 30 pF								
t _W	pulse width	LE HIGH; see Figure 8								
		V _{CC} = 0.8 V	-	4.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.7	-	2.1	-	2.1	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.5	-	1.3	-	1.3	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	1.0	-	1.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.3	-	0.8	-	0.8	-	ns
				0.2		0.8		0.8		

Low-power D-type transparent latch; 3-state

 Table 8.
 Dynamic characteristics ...continued

Symbol	Parameter	Conditions		25 °C			-40 °C 1	to +125 °C	;	Unit
			Min	Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
t _{su(H)}	set-up time	D to LE; see Figure 9	'				1			
	HIGH	$V_{CC} = 0.8 \text{ V}$	-	4.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.9	-	2.2	-	2.2	-	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	0.6	-	1.4	-	1.4	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	0.4	-	1.0	-	1.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	0	-	0.6	-	0.6	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	-0.1	-	0.4	-	0.4	-	ns
	set-up time	D to LE; see Figure 9								
	LOW	$V_{CC} = 0.8 \text{ V}$	-	4.0	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	1.2	-	2.7	-	2.7	-	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	0.7	-	1.5	-	1.5	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	0.6	-	1.2	-	1.2	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	0.4	-	0.9	-	0.9	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	0.3	-	0.7	-	0.7	-	ns
t _h	hold time	D to LE HIGH or LOW; see Figure 9								
		$V_{CC} = 0.8 \text{ V}$	-	-4.6	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	-0.9	-	-0.1	-	-0.1	-	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	-0.6	-	-0.1	-	-0.1	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	-0.4	-	0	-	0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-0.2	-	0.2	-	0.2	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	-0.1	-	0.3	-	0.3	-	ns

 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 11.

Symbol	Parameter			25 °C		–40 °C to +125 °C				Unit	
				Min	Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C_{PD}	power	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$	[5][6]								
	dissipation capacitance	output enabled									
		V _{CC} = 0.8 V		-	2.0	-	-	-	-	-	pF
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		-	2.0	-	-	-	-	-	pF
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		-	2.0	-	-	-	-	-	pF
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-	2.1	-	-	-	-	-	pF
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	2.4	-	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	2.8	-	-	-	-	-	pF

- [1] All typical values are measured at nominal V_{CC}.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] t_{en} is the same as t_{PZH} and t_{PZL} .
- [4] t_{dis} is the same as t_{PHZ} and t_{PLZ} .
- [5] All specified values are the average typical values over all stated loads.
- [6] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

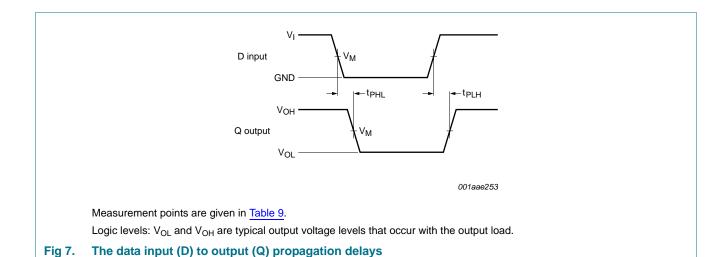
 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs;

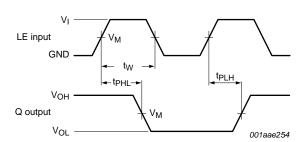
N = number of inputs switching.

12. Waveforms



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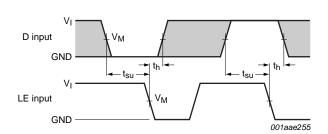
Low-power D-type transparent latch; 3-state



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8. The latch enable input (LE) to output (Q) propagation delays, the latch enable input (LE) pulse width



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 9. Data set-up and hold times for the D input to the LE input

Table 9. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	V _I	$t_r = t_f$
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V_{CC}	≤ 3.0 ns

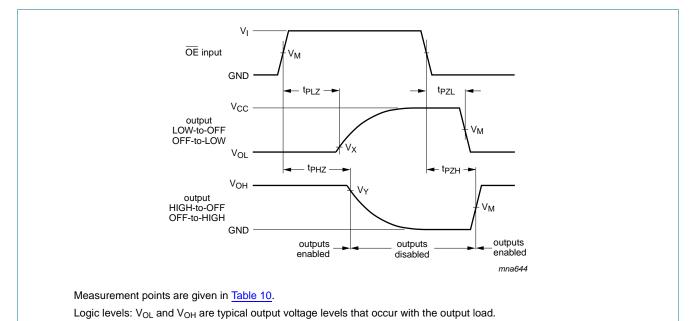


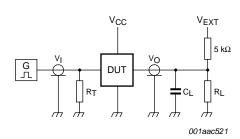
Fig 10. Turn-on and turn-off times

Table 10. Measurement points

Supply voltage	Input	Output					
V _{CC}	V _M	V _M	V _X	V _Y			
0.8 V to 1.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.1 V	$V_{OH} - 0.1 V$			
1.65 V to 2.7 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.15 V	V _{OH} – 0.15 V			
3.0 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.3 V	V _{OH} – 0.3 V			

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Low-power D-type transparent latch; 3-state



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 11. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	C _L	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times R_L = 5 $k\Omega$, for measuring propagation delays, setup and hold times and pulse width R_L = 1 $M\Omega$.

13. Package outline

Plastic surface-mounted package; 6 leads

SOT363

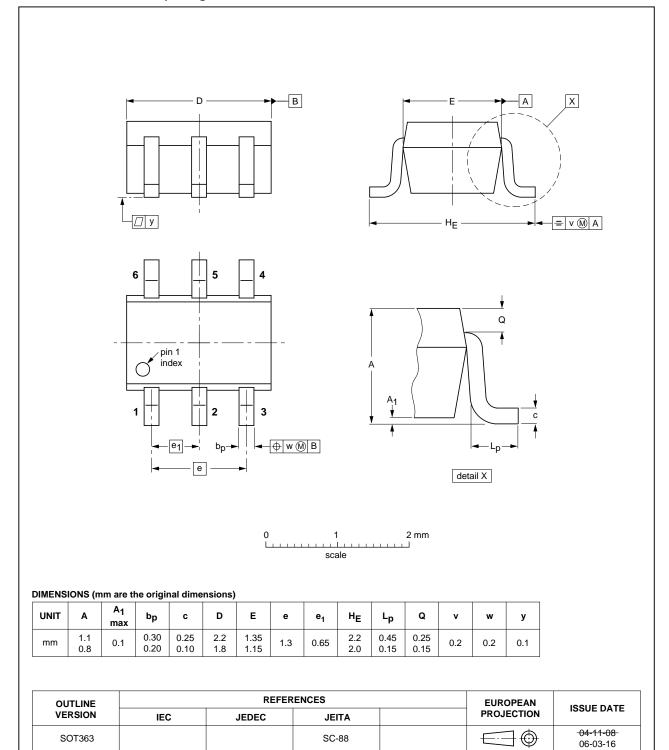


Fig 12. Package outline SOT363 (SC-88)

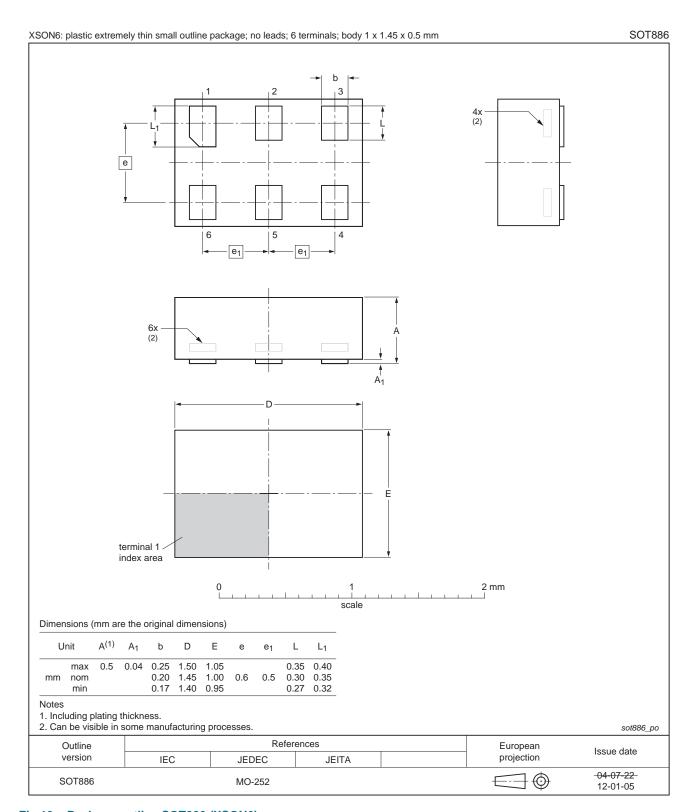


Fig 13. Package outline SOT886 (XSON6)

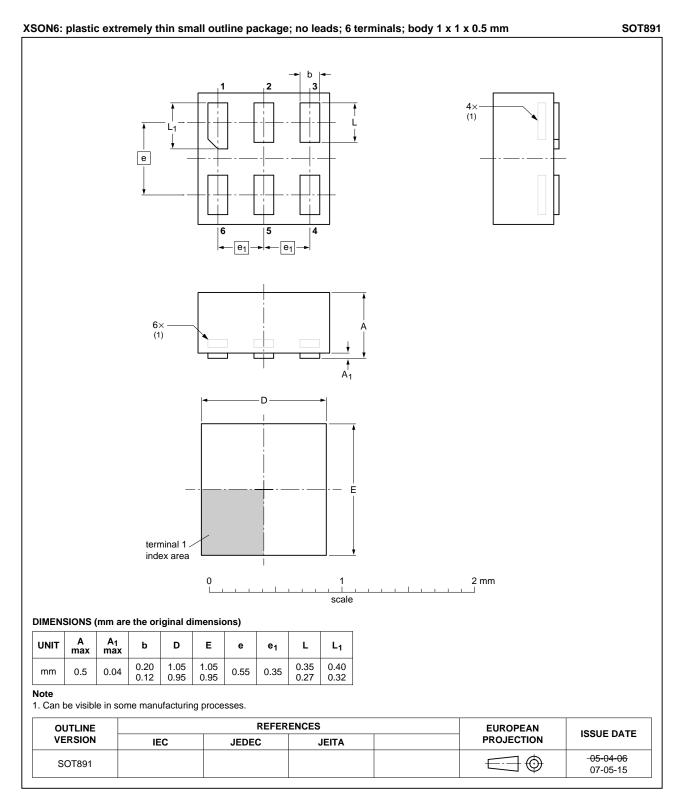


Fig 14. Package outline SOT891 (XSON6)

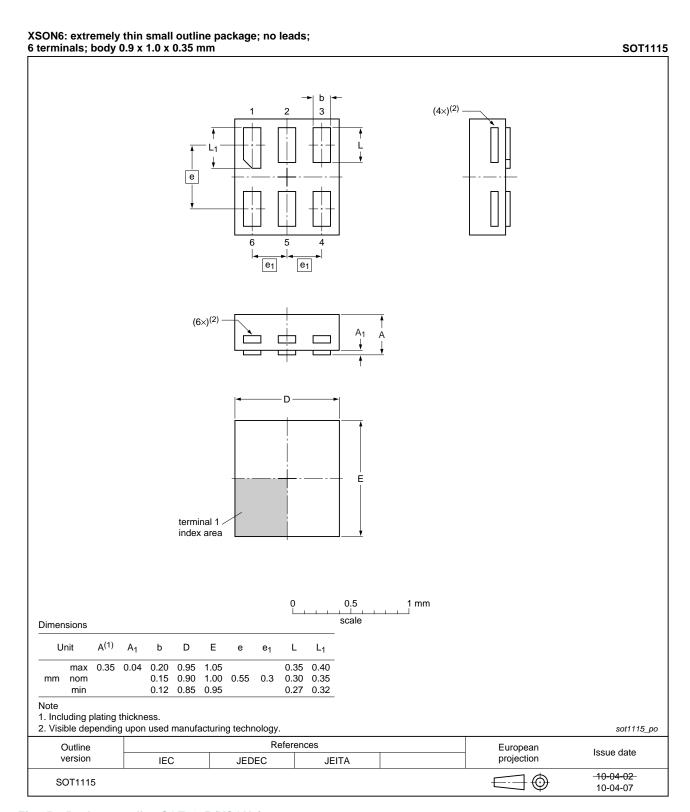


Fig 15. Package outline SOT1115 (XSON6)

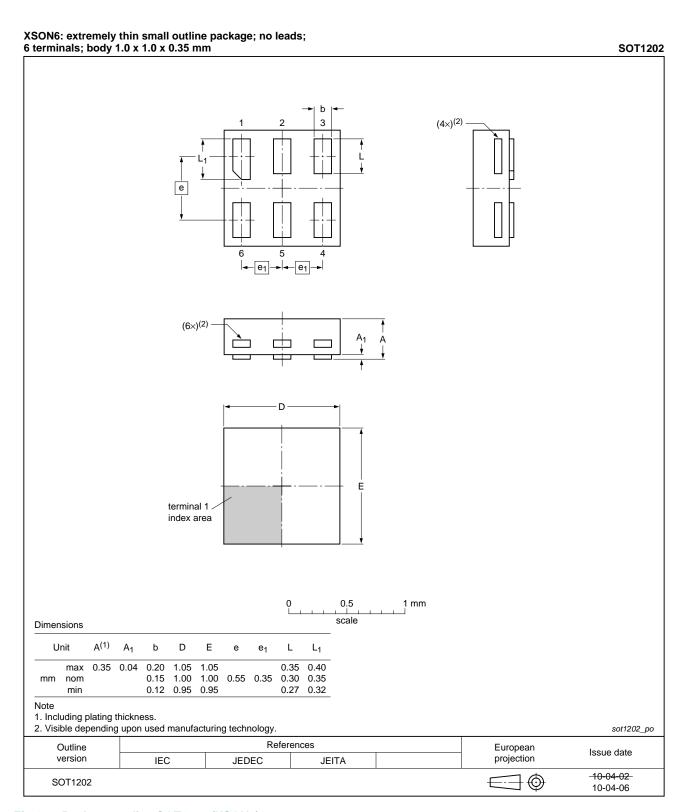


Fig 16. Package outline SOT1202 (XSON6)

14. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

15. Revision history

Table 13. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G373 v.6	20120704	Product data sheet	-	74AUP1G373 v.5
Modifications:	 Package ou 	ıtline drawing of SOT886 (Figure 13) modified.	
74AUP1G373 v.5	20111125	Product data sheet	-	74AUP1G373 v.4
Modifications:	 Legal pages 	s updated.		
74AUP1G373 v.4	20100715	Product data sheet	-	74AUP1G373 v.3
74AUP1G373 v.3	20080109	Product data sheet	-	74AUP1G373 v.2
74AUP1G373 v.2	20070720	Product data sheet	-	74AUP1G373 v.1
74AUP1G373 v.1	20061129	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

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